

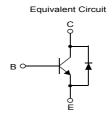
FJD5304D

High Voltage Fast Switching Transistor

Features

- Built-in Free Wheeling Diode
- · Wide Safe Operating Area
- Small Variance in Storage Time
- · Suitable for Electronic Ballast Application





Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	700	V
V _{CEO}	Collector-Emitter Voltage	400	V
V _{EBO}	Emitter-Base Voltage	12	V
I _C	Collector Current (DC)	4	A
I _{CP}	* Collector Current (Pulse)	8	A
I _B	Base Current (DC)	2	A
I _{BP}	* Base Current (Pulse)	4	A
P _C	Collector Dissipation (T _C = 25°C)	30	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

^{*} Pulse Test: PW = $300\mu s$, Duty Cycle = 2% Pulsed

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
J5304D	FJD5304DTM	D-PAK	13" Dia	-	2500
J5304D	FJD5304DTF	D-PAK	13" Dia	-	2000

Electrical Characteristics T_C = 25°C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Тур.	Max	Units
BV _{CBO}	Collector-Base Breakdown Voltage	I _C = 1mA, I _E = 0	700			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C = 5mA, I _B = 0	400			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E = 1mA, I _C = 0	12			V
I _{CES}	Collector Cut-off Current	V _{CB} = 700V, I _E = 0			100	μΑ
I _{CEO}	Collector Cut-off Current	V _{CB} = 400V, I _B = 0			250	μΑ
I _{EBO}	Emitter Cut-off Current	V _{EB} = 12V, I _C = 0			1	mA
h _{FE}	DC Current Gain	V _{CE} = 5V, I _C = 10mA V _{CE} = 5V, I _C = 2.0A	10 8		40	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 0.5A, I _B = 0.1A			0.7	V
		I _C = 1.0A, I _B = 0.2A			1.0	V
		$I_C = 2.5A, I_B = 0.5A$			1.5	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 0.5A, I _B = 0.1A			1.1	V
		I _C = 1.0A, I _B = 0.2A			1.2	V
		I _C = 2.5A, I _B = 0.5A			1.3	V
t _{STG}	Storage Time	V _{CLAMP} =200V, I _C =2.0A		0.6		μ\$
t _F	Fall Time	I _{B1} =0.4A, V _{BE} (off)=-5V, L=200μH		0.1		μS
t _{STG}	Storage Time	V _{CC} =250V, I _C =2.0A			2.9	μS
t _F	Fall Time	I _{B1} =0.4A, I _{B2} =-0.4A, T _P =30μs		0.2		μS

Typical Performance Characteristics

Figure 1. Static Characterstic

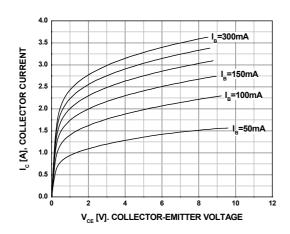


Figure 2. DC Current Gain

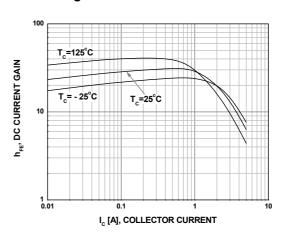


Figure 3. Collector-Emitter Saturation Voltage

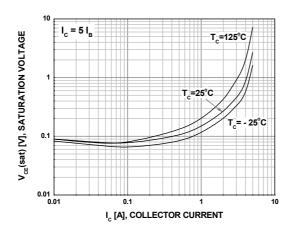


Figure 4. Base-Emitter Saturation Voltage

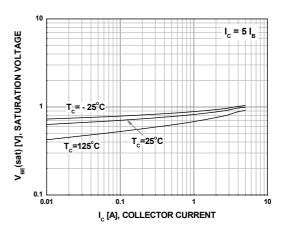


Figure 5. Resistive Load Switching Time

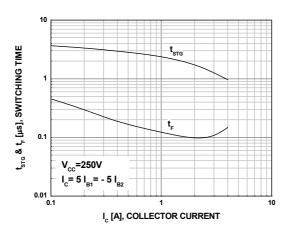
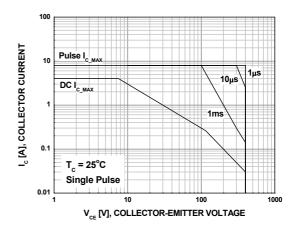


Figure 6. Forward Biased Safe Operating Area



Typical Performance Characteristics (Continued)

Figure 7. Reverse Biased Safe Operating Area

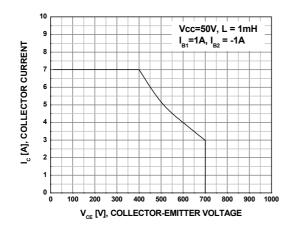
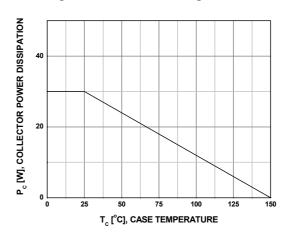
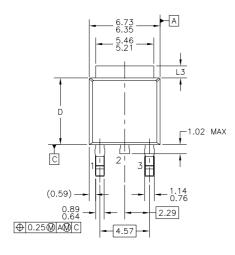


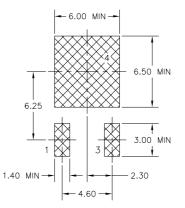
Figure 8. Power Derating Curve



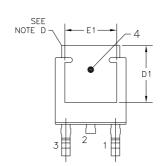
Mechanical Dimensions

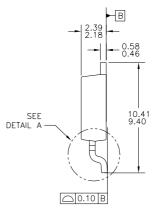
D-PAK

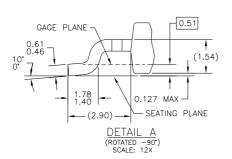




LAND PATTERN RECOMMENDATION







- NOTES: UNLESS OTHERWISE SPECIFIED

 A) ALL DIMENSIONS ARE IN MILLIMETERS.

 B) THIS PACKAGE CONFORMS TO JEDEC, TO-252, ISSUE C, VARIATION AA & AB, DATED NOV. 1999.

 C) DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.

 D) HEAT SINK TOP EDGE COULD BE IN CHAMFERED CORNERS OR EDGE PROTRUSION.

 E) DIMENSIONS L3,D,E1&D1 TABLE:

DINIENSIONS ES,D,ETADT IN				
		OPTION AA	OPTION AB	
	L3	0.89-1.27	1.52-2.03	
	D	5.97-6.22	5.33-5.59	
	E1	4.32 MIN	3.81 MIN	
	D1	5.21 MIN	4.57 MIN	

PRESENCE OF TRIMMED CENTER LEAD IS OPTIONAL.

Dimensions in Millimeters

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CoolFET™	FRFET™	MicroFET™	PowerTrench [®]	SuperSOT™-6
CROSSVOLT™	GlobalOptoisolator™	MicroPak™	QFET [®]	SuperSOT™-8
DOME™	GTO™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	HiSeC™	MSX™	QT Optoelectronics™	TinyLogic [®]
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EnSigna™	i-Lo™	OCX™	RapidConfigure™	TruTranslation™
FACT™	ImpliedDisconnect™	OCXPro™	RapidConnect™	UHC™
FACT Quiet Series™		OPTOLOGIC [®]	μSerDes™	UltraFET [®]
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		PACMAN™	SMART START™	
		DODIM	CDMIM	

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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Definition of Terms

Datasheet Identification	Product Status	Definition
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